NSN 5962-01-197-5027

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View Online at https://aerobasegroup.com/nsn/5962-01-197-5027 **Body Length:** Between 0.750 inches and 0.785 inches **Body Width:** 0.250 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 512.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 5895-01-101-1980 control, antenna **Features Provided:** Hermetically sealed and burn in and w/resistor and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Unit Of Measure:

Shelf Life:

16 printed circuit

Terminal Type And Quantity:

N/a

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Demilitarization:

Yes - demil/mli

Fiig:

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